

P40B10SN

Power MOSFETs

100V, 40A, N-channel

Feature

- N-channel
- SMD
- Low Ron
- 10V Gate Drive
- Low Capacitance
- Pb free terminal
- RoHS:Yes

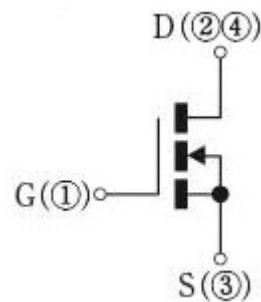
OUTLINE

Package (House Name): FB

Package (JEDEC Code): TO-252AA



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 150	°C
Channel tempertature	Tch		-55 to 150	°C
Drain-source voltage	V <sub>DSS</sub>		100	V
Gate-source voltage	V <sub>GSS</sub>		±20	V
Continuous drain current(DC)	I <sub>D</sub>		40	A
Continuous drain current(Peak)	I <sub>DP</sub>	Pulse width 10μs, duty=1/100	120	A
Total power dissipation	P <sub>T</sub>		62.5	W
Single avalanche current	I <sub>AS</sub>	Starting Tch=25°C Tch≤150°C	28	A
Single avalanche energy	E <sub>AS</sub>	Starting Tch=25°C Tch≤150°C	88	mJ

※ :See the original Specifications

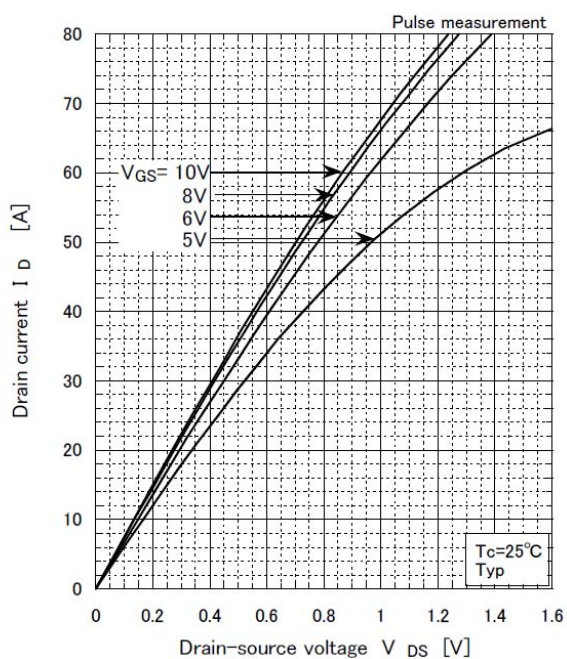
**Electrical Characteristics** (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	100			V
Zero gate voltage drain current	$I_{DSS}$	VDS=100V, VGS=0V			1	μA
Gate-source leakage current	$I_{GSS}$	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	$g_{fs}$	ID=20A, VDS=10V	12	24		S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=20A, VGS=10V		0.0134	0.0168	Ω
Gate threshold voltage	$V_{th}$	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	$V_{SD}$	IS=40A, VGS=0V			1.5	V
Thermal resistance	$R_{th(j-c)}$	Junction to case, with heatsink ※			2	°C/W
Total gate charge	$Q_g$	VDD=80V, VGS=10V, ID=40A		56		nC
Gate to source charge	$Q_{gs}$	VDD=80V, VGS=10V, ID=40A		15		nC
Gate to drain charge	$Q_{gd}$	VDD=80V, VGS=10V, ID=40A		19.5		nC
Input capacitance	$C_{iss}$	VDS=25V, VGS=0V, f=1MHz		2880		pF
Reverse transfer capacitance	$C_{rss}$	VDS=25V, VGS=0V, f=1MHz		122		pF
Output capacitance	$C_{oss}$	VDS=25V, VGS=0V, f=1MHz		258		pF
Turn-on delay time	$t_{d(on)}$	ID=20A, RL=2.5Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		7		ns
Rise time	$t_r$	ID=20A, RL=2.5Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		17		ns
Turn-off delay time	$t_{d(off)}$	ID=20A, RL=2.5Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		31		ns
Fall time	$t_f$	ID=20A, RL=2.5Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		14		ns
Diode reverse recovery time	$t_{rr}$	IF=40A, VGS=0V, di/dt=100A/μs		54		ns
Diode reverse recovery charge	$Q_{rr}$	IF=40A, VGS=0V, di/dt=100A/μs		108		nC

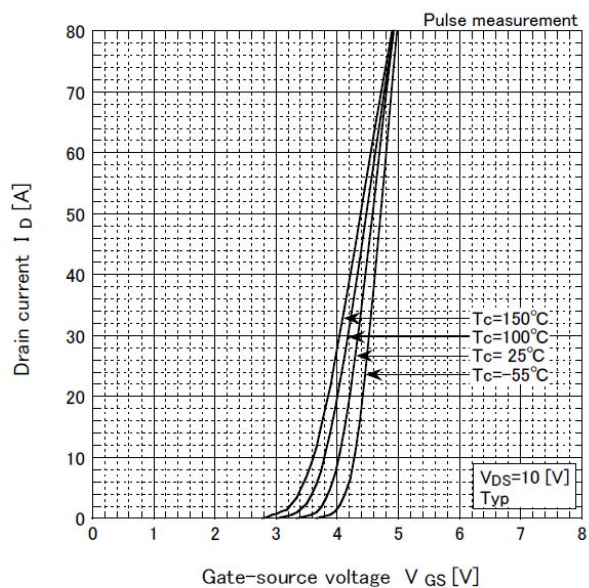
※ :See the original Specifications

## CHARACTERISTIC DIAGRAMS

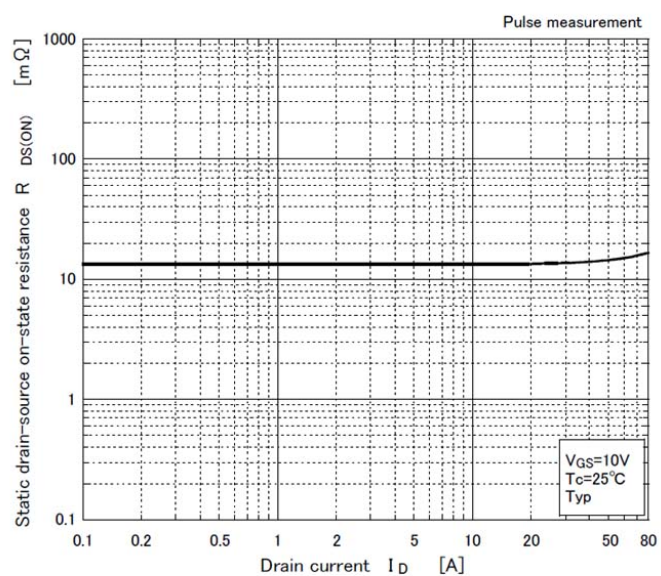
Typical output characteristics



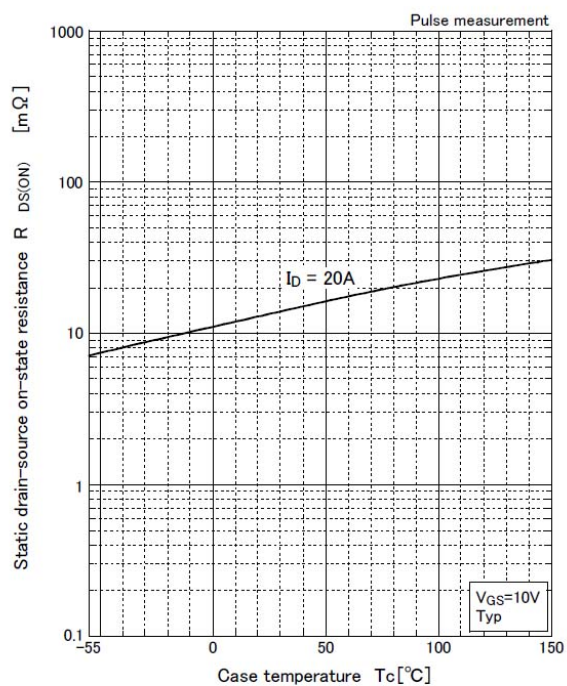
Transfer characteristics

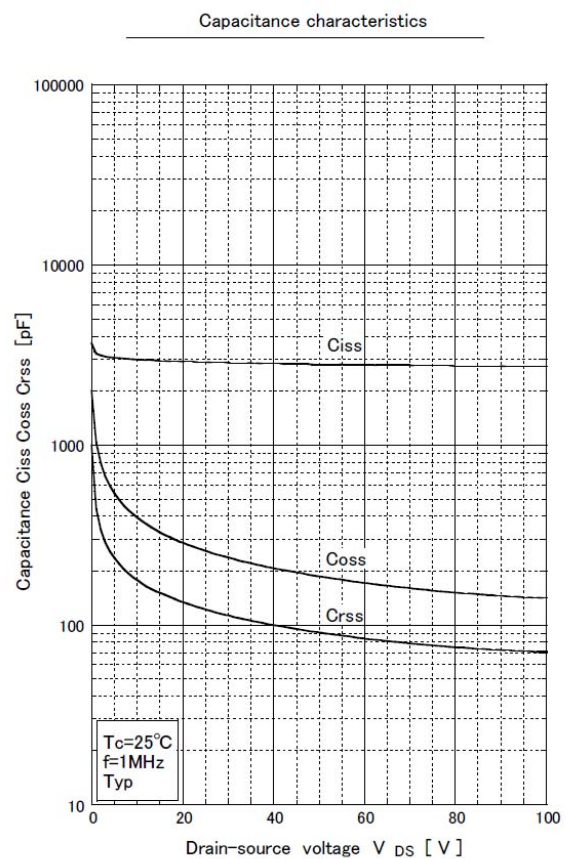
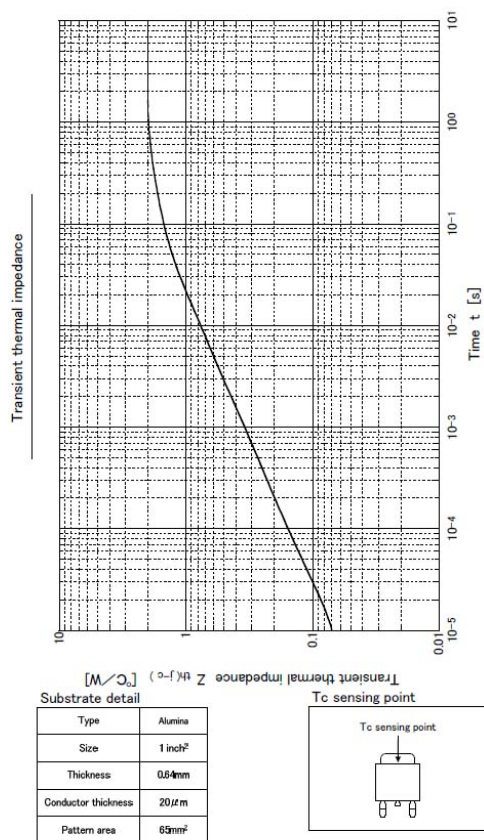
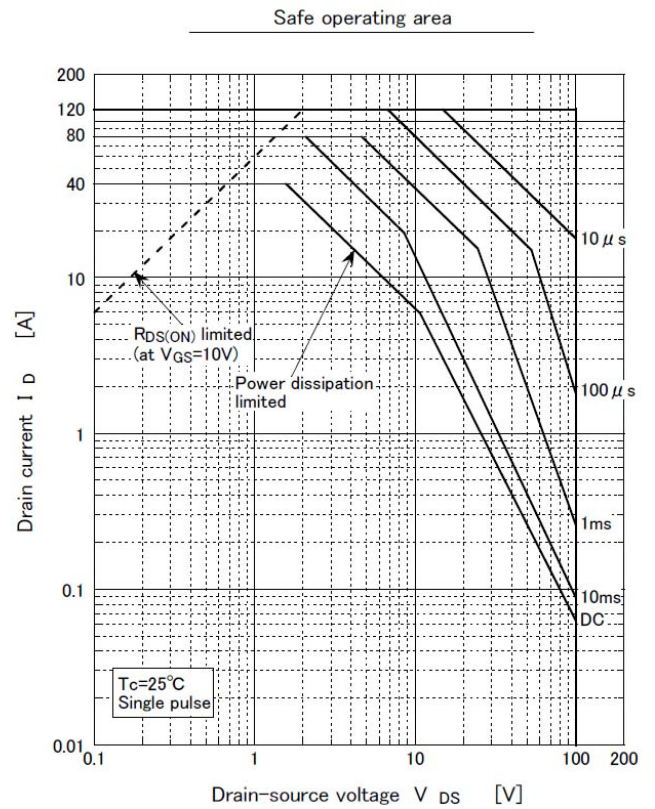
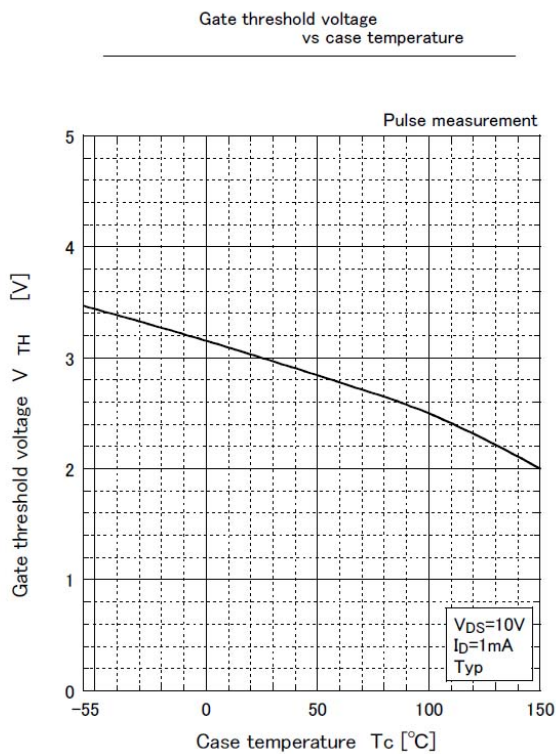


Static drain-source on-state resistance vs drain current



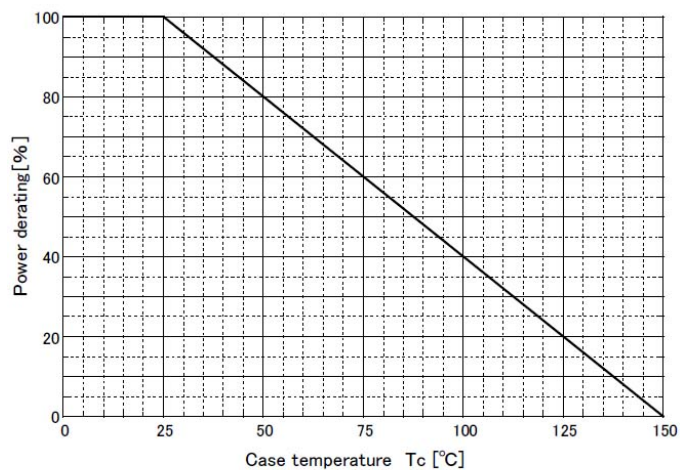
Static drain-source on-state resistance vs case temperature



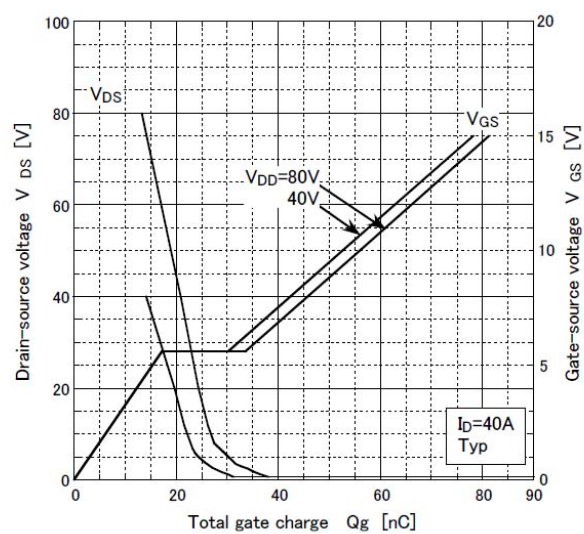




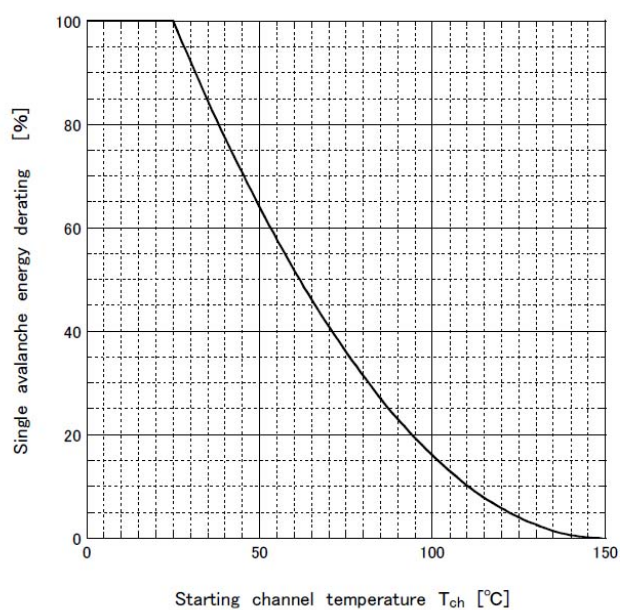
Power derating – case temperature



Gate charge characteristics

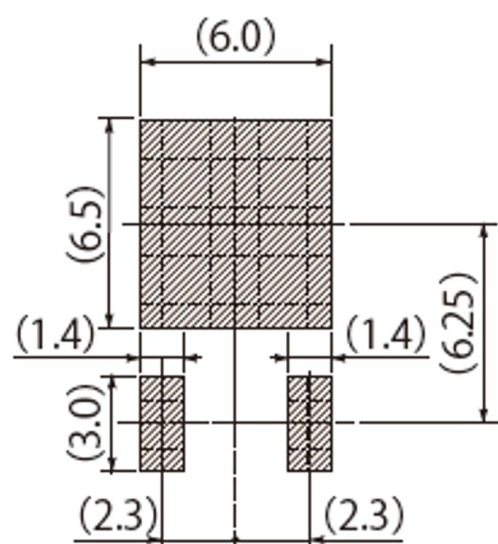
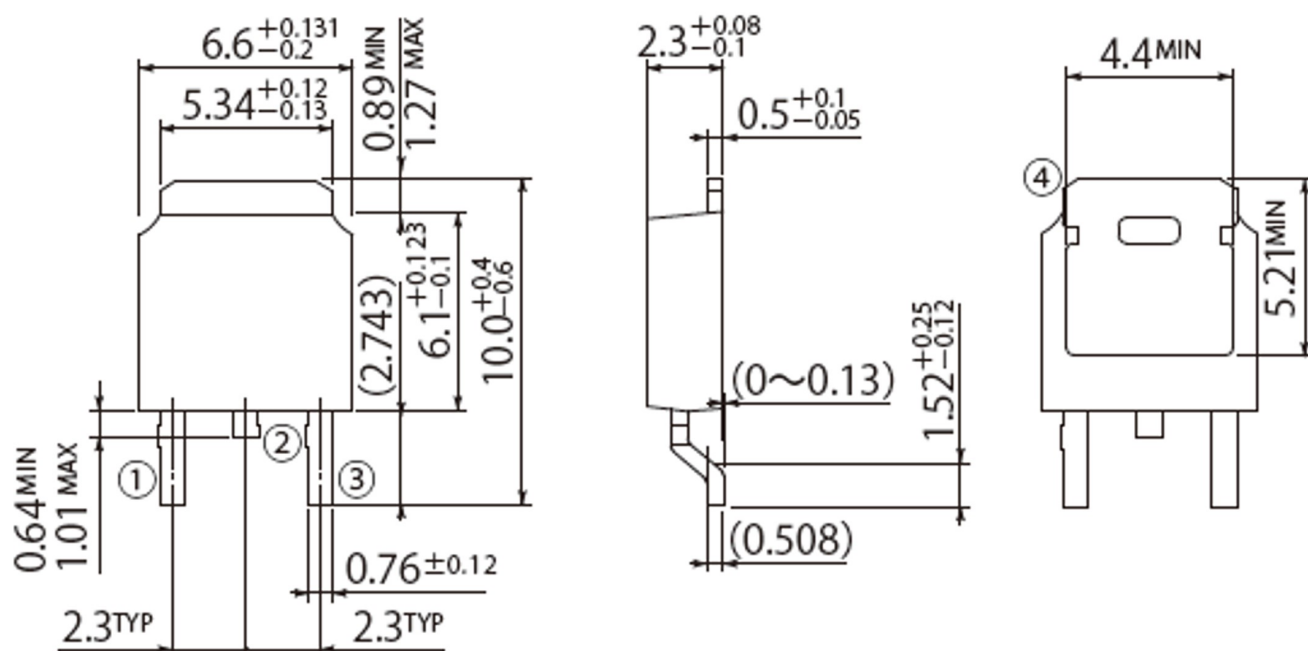


Single avalanche energy derating  
vs channel temperature



G2

JEDEC Code	TO-252AA
JEITA Code	-
House Name	FB



Referential Soldering Pad

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